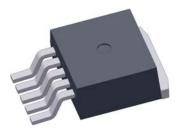


DC-to-DC Step-Down Converter

Features and Benefits

- 5.5 A output current supplied in a small, surface mount power package
- High efficiency: 83% at V_{IN} =15 V, I_O =3.0 A, V_O =5 V
- Requires only seven external components (optional soft start requires an additional capacitor)
- Oscillation circuit built-in (frequency 150 kHz typical)
- Constant-current mode overcurrent protection circuit and overtemperature protection circuit built-in
- Soft start function built-in (can be implemented as an on/off function; output-off state at low level)
- Low current consumption during output-off state

Package: TO263-5



Description

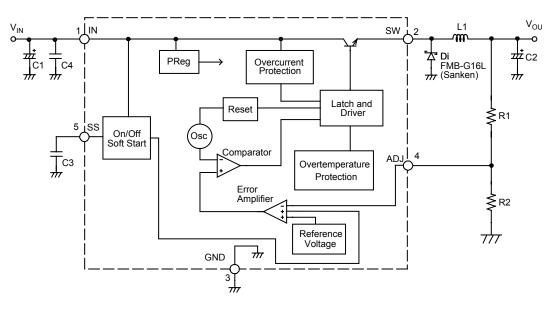
The SI-8008HD DC voltage regulator is a DC-to-DC buck convertor that attains an oscillation frequency of 150 kHz, and has an integrated miniaturized choke coil, allowing it to serve as a small, high efficiency power supply in a compact TO-263 package.

The internal switching regulator function provides high efficiency switching regulation without any need for adjustment. The device requires only six external support components. The optional soft start function requires an additional capacitor. Optional on/off control can be performed using a transistor. The SI-8008HD includes overcurrent and overtemperature protection circuits.

Applications include:

- DVD recorder
- FPD TV
- Telecommunications equipment
- Office automation equipment, such as printers
- On-board local power supply
- Output voltage regulator for second stage of SMPS (switched mode power supply)

Not to scale



Functional Block Diagram

DC-to-DC Step-Down Converter

Selection Guide

Part Number	Output Voltage Adjustable Range (V)	Efficiency, Typ. (%)	Input Voltage, Max. (V)	Output Current, Max. (A)	Packing
SI-8008HD-TL	0.8 to 24	83	40	5.5	800 pieces per reel

Absolute Maximum Ratings

Characteristic	Symbol	Remarks	Rating	Units
DC Input Voltage	V _{IN}		43	V
Power Dissipation	P _D	Mounted on 40 mm × 40 mm exposed copper area on 40 mm × 40 mm glass-epoxy PCB; limited by internal overtemperature protection.	3	W
Junction Temperature	TJ	Internal overtemperature protection circuit may enable when $T_J \ge 130^{\circ}$ C. During product operation, recommended $T_J \le 125^{\circ}$ C.	-40 to 150	°C
Storage Temperature	T _{stg}		-40 to 150	°C
Thermal Resistance (junction-to-case)	$R_{ ext{ heta}JC}$	Mounted on 40 mm × 40 mm exposed copper area on 40 mm × 40 mm glass-epoxy PCB.	3	°C/W
Thermal Resistance (junction-to-ambient air)	$R_{ heta JA}$	Mounted on 40 mm × 40 mm exposed copper area on 40 mm × 40 mm glass-epoxy PCB.	33.3	°C/W

Recommended Operating Conditions*

Characteristic	Symbol	Remarks	Min.	Max.	Units
DC Input Voltage Range	V _{IN}	$V_{\rm IN}(\rm min)$ is the greater of 4.5 V or $V_{\rm O}\text{+}3$ V.	See remarks	40	V
DC Output Voltage Range	Vo		0.8	24	V
DC Output Current Range	Ι _Ο	$V_{IN} \ge V_O + 3 V$; to be used within the allowable package power dissipation characteristics (refer to Power Dissipation chart).	0	3.5	А
Operating Junction Temperature Range	T _{JOP}		-30	100	°C
Operating Temperature Range	T _{OP}	To be used within the allowable package power dissipation characteristics (refer to Power Dissipation chart).	-30	85	°C

*Required for normal device functioning according to Electrical Characteristics table.

All performance characteristics given are typical values for circuit or system baseline design only and are at the nominal operating voltage and an ambient temperature, T_A , of 25°C, unless otherwise stated.





ELECTRICAL CHARACTERISTICS¹, valid at T_A = 25°C, V_O = 5 V (adjusted), R1 = 4.2 k Ω , R1 = 0.8 k Ω

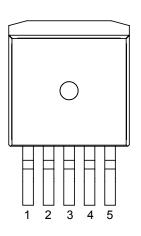
Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Reference Voltage	V _{ADJ}	V _{IN} = 15 V, I _O = 0.2 A	0.784	0.800	0.816	V
Reference Voltage Temperature Coefficient	$\Delta V_{ADJ} / \Delta T$	V_{IN} = 15 V, I_{O} = 0.2 A, T_{C} = 0 to 100 °C	-	±0.1	-	mV/°C
Efficiency ²	η	V _{IN} = 15 V, I _O = 3 A	-	83	-	%
Operating Frequency	f _O	V _{IN} = 15 V, I _O = 3 A	_	150	-	kHz
Line Regulation	V _{Line}	V_{IN} = 10 to 30 V, I_{O} = 3 A	-	60	80	mV
Load Regulation	V _{Load}	V_{IN} = 15 V, I_O = 0.2 to 5.5 A	-	20	50	mV
Overcurrent Protection Threshold Current	Is	V _{IN} = 15 V	5.6	6.5	7.5	А
SS Terminal On/Off Operation Threshold Voltage	V _{SSL}		-	-	0.5	V
SS Terminal On/Off Operation Outflow Current	I _{SSL}	V _{SSL} = 0 V	_	10	30	μA
Quiescent Current 1	lq	V _{IN} = 15 V, I _O = 0 A	_	6	-	mA
Quiescent Current 2	I _{q(off)}	V _{IN} = 15 V, V _{SS} = 0 V	-	200	400	μA

¹Using circuit shown in Typical Application Circuit diagram.

²Efficiency is calculated as: $\eta(\%) = ([V_O \times I_O] \times [V_{IN} \times I_{IN}]) \times 100$.

Pin-out Diagram

Terminal List Table



Name	Number	Function			
IN	1	Supply voltage			
SW	2	Regulated supply output			
GND	3	Ground terminal			
ADJ	4	Terminal for resistor bridge feedback			
SS	5	The SS terminal is used to enable soft start and to control on/off operation of the IC output, V_O (see figure 2). If neither soft start nor on/off control is used, leave pin open. To enable soft start, connect a capacitor between SS and ground. To control on/off operation, connect an NPN bipolar transistor, in a TTL open collector output configuration, between the SS terminal and GND. Turn off is done by decreasing V_{SSL} below its rated level. When both soft start and V_O on/off are used, a protection measure such as current limiting is required because, if the capacitance of C3 large, the discharge current of C3 flows across the transistor for on/off operation. Because a pull-up type resistor is provided inside the IC, no external voltage can be applied.			

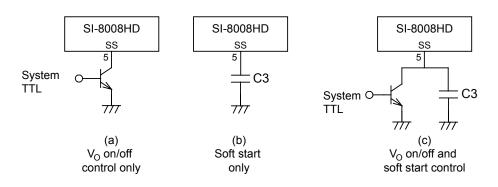
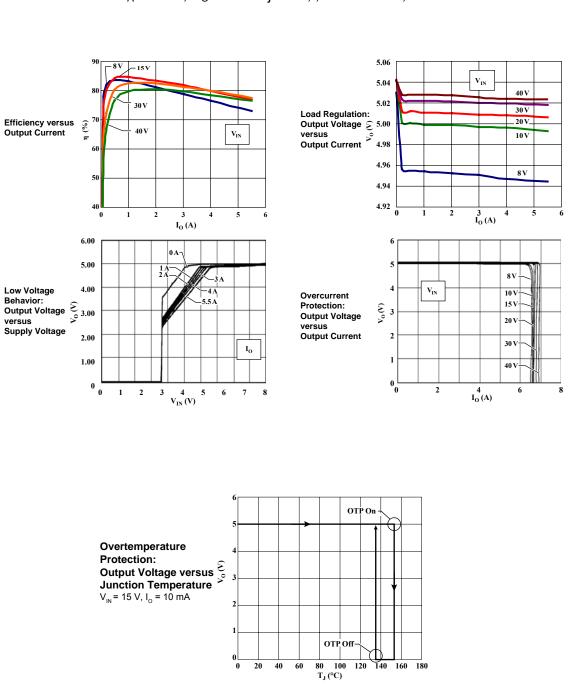


Figure 2. Alternative configurations for SS pin. If neither soft start nor Vo on/off is required, the SS pin is left open.





DC-to-DC Step-Down Converter



Performance Characteristics at $T_A = 25^{\circ}$ C, $V_O = 5 V$ adjusted, , R1 = 4.2 k Ω , R2 = 0.8 k Ω





DC-to-DC Step-Down Converter

Power Dissipation versus Ambient Temperature

Thermal Performance Characteristics

The application must be designed to ensure that the $T_J(max)$ of the device is not exceeded during operation. To do so, it is necessary to determine values for maximum power dissipation, $P_D(max)$, and ambient temperature, $T_A(max)$.

The relationships of T_J , P_D , T_A , and case temperature, T_C , are as shown in the following formulas:

$$P_{\rm D} = \frac{T_J - T_C}{R_{\rm \theta IC}}$$
 and $P_{\rm D} = \frac{T_{\rm J} - T_{\rm A}}{R_{\rm \theta JA}}$

P_D can be calculated from input values:

$$P_D = V_O \cdot I_O \left(\frac{100}{\eta_x} - 1\right) - V_F \cdot I_O \left(1 - \frac{V_O}{V_{IN}}\right)$$

where:

Vo is output voltage in V,

V_{IN} is input supply voltage in V,

I₀ is output current in A,

 η_x is IC efficiency in percent (varies with $V_{\rm IN}$ and $I_O;$ refer to efficiency performance curves for value), and

 $V_{\rm F}\,$ is forward voltage for the input diode, Di. In these tests, the Sanken FMB-G16L was used, at 0.55 V. For application design, obtain thermal data from the datasheet for the diode.

 P_D is substantially affected by the heat conductance properties of the application, in particular any exposed copper area on the PCB where the device is mounted. The relationships of P_D , T_A , and copper area is represented in the Power Dissipation chart.

 $R_{\theta JA}$ for a given copper area can be determined form the Device Thermal Resistance chart. This can be substituted into the formula above to determine the T_J (max) allowable in the application. Generally, more than 10% to 20% derating is required.

Because the heat dissipation capacity of the copper area depends substantively on how it is used in the actual application, thermal characteristics of the application must be confirmed by testing. T_C is determined by connecting a thermocouple to the device as shown here:

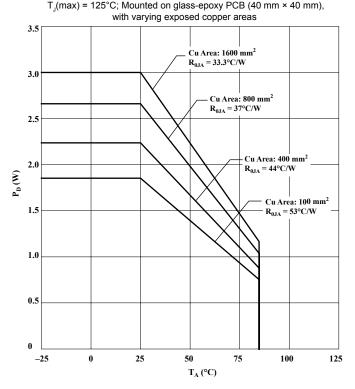


And analyzing the results using the following formula:

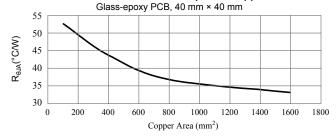
$$T_{\rm J} = P_{\rm D} \times R_{\rm \theta JC} + T_C$$

for this device, $R_{\theta JC}$ is 3 °C/W.

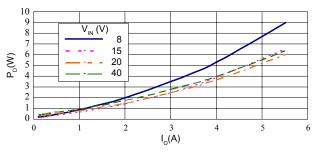




Device Thermal Resistance versus Exposed Copper Area on PCB



Power Dissipation versus Output Current





DC-to-DC Step-Down Converter

Component Selection

Diode Di A Schottky-barrier diode must be used for Di. If other diode types are used, such as fast recovery diodes, the IC may be destroyed because of the reverse voltage applied by the recovery voltage or ON voltage.

Choke Coil L1 If the winding resistance of the choke coil is too high, the efficiency may be reduced below rating. Because the overcurrent protection start current is approximately 6.5 A, attention must be paid to the heating of the choke coil by magnetic saturation due to overload or short-circuited load.

Capacitors C1, C2, C3, and C4 Because for SMPS, large ripple currents flow across C1 and C2, capacitors with high frequency and low impedance must be used. If the impedance of C2 is too high, the switching waveform may not be normal at low temperatures. Do not use either OS or tantalum types of capaci-

tors for C2, because those cause an abnormal oscillation.

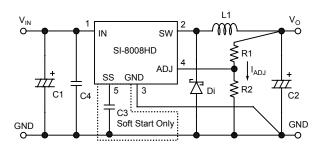
The device is stabilized, and for proper operation, C1 and C4 must be located close to the device (see layout diagram, below). C3 is required only if the soft start function is used. If not using soft-start, leave the SS terminal open. A pull-up resistor is provided inside the IC.

Resistor Bridge R1 and R2 comprise the resistor bridge for the output voltage, V₀, and are calculated as follows:

$$RI = \frac{(V_0 - V_{ADJ})}{I_{ADJ}} = \frac{(V_0 - 0.8)}{1 \times 10^{-3}} (\Omega) \text{, and } R2 = \frac{V_{ADJ}}{I_{ADJ}} = \frac{0.8}{1 \times 10^{-3}} = 0.8 (k\Omega)$$

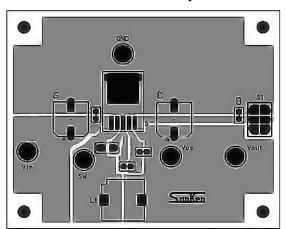
 I_{ADJ} should always be set to 1 mA. Note that R2 should always be present to ensure stable operation, even if V_O , is set to 0.8 V (that is, even if there is no R1). V_O should be at least $V_{IN} + 8\%$.

Typical Application Diagram



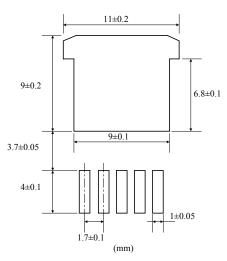
Component	Rating
C1	1500 μF
C2	1000 μF
C3	0.1 µF (For soft start function)
C4	4.7 μF (GRM32ER71H475KA88L)
Di	FMB-G16L (Sanken)
L1	100 µH

Recommended PCB Layout



All external components should be mounted as close as possible to the SI-8008HD. The ground of all components should be connected at one point near GND pin (pin 3).

Recommended Solder Pad Layout

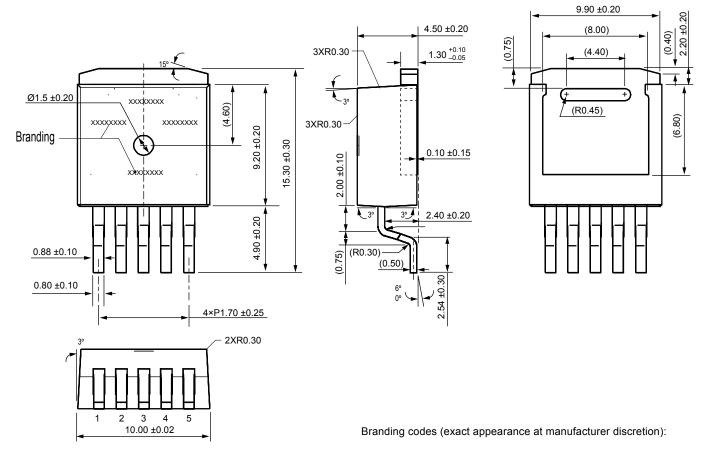






DC-to-DC Step-Down Converter

PACKAGE OUTLINE DRAWING



Dimensions do not include mold protrusion Heastsink side flash: 0.8 mm maximum

Dimensions in millimeters

 1st line:
 SK

 2nd line, lot:
 YMW X

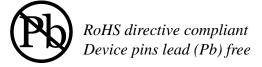
 Where: Y is the last digit of the year of manufacture

 M is the month (1 to 9, O, N, D)

 W is the week of the month (1 to 5)

 X is the device subtype suffix number

 3rd line, type:
 8008HD

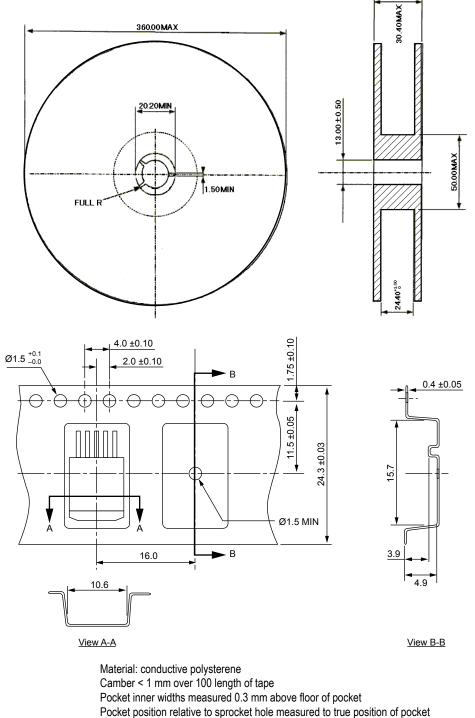






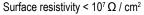
DC-to-DC Step-Down Converter

TAPE AND REEL SPECIFICATION



10 sprocket hole pitch cumulative ±0.2 mm

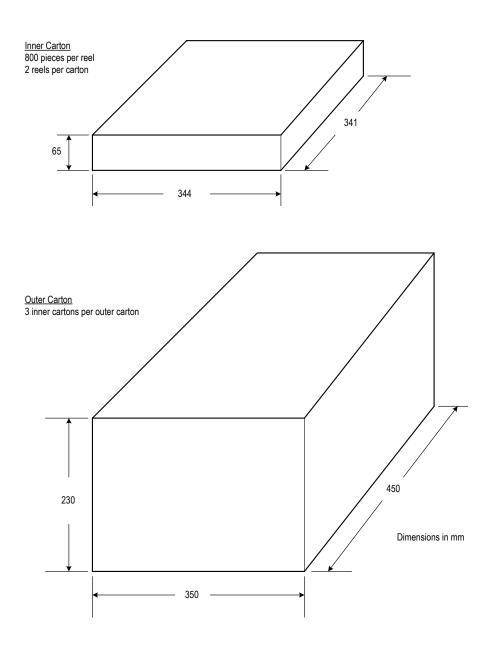
Pocket center and pocket hole center ±0.3 mm







PACKING SPECIFICATION







DC-to-DC Step-Down Converter



WARNING — These devices are designed to be operated at lethal voltages and energy levels. Circuit designs that embody these components must conform with applicable safety requirements. Precautions must be taken to prevent accidental contact with power-line potentials. Do not connect grounded test equipment.

The use of an isolation transformer is recommended during circuit development and breadboarding.

Cautions for Use

- Operation of the product in parallel to increase current is not permitted.
- Although the product has an internal overtemperature protection circuit, that is intended only to protect the product from temporary excess heating due to overloads. Long-term reliability cannot be guaranteed when the product is operated under continuous overload conditions.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

Cautions for Storage

- Ensure that storage conditions comply with the standard temperature (5°C to 35°C) and the standard relative humidity (around 40 to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of products that have been stored for a long time.

Cautions for Testing and Handling

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between adjacent products, and shorts to the heatsink.

Electrostatic Discharge

- When handling the products, operator must be grounded. Grounded wrist straps worn should have at least 1 MΩ of resistance to ground to prevent shock hazard.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- · When soldering the products, the head of soldering irons or the

solder bath must be grounded in other to prevent leak voltages generated by them from being applied to the products.

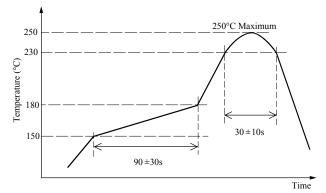
 The products should always be stored and transported in our shipping containers or conductive containers, or be wrapped in aluminum foil.

Soldering

• When manually soldering the products, please be sure to minimize the working time, within the following limits:

Soldering Iron Temperature	Time
(°C)	(s)
380±10	3 (once only)

• Reflow soldering can be performed a maximum of twice, using the following recommended profile:







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DC-to-DC Step-Down Converter SI-8008HD



January, 2008

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